

Description

The ASM712 is designed for asymmetrical (12V to -7V) protection in multi-point data transmission application, The ASM712 replace four discrete components by integrating two 12V and two 7V TVS diodes in a single package. The ASM712 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a lead-free SOT-23 package. It is designed to protect components which are connected to data and transmission lines from voltage surges.

Features

- 325W peak pulse power (8/20µs)
- Ultra low leakage: nA level
- Operating voltage: 7V or 12V
- Low clamping voltage
- · Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV
Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 13A (8/20μs)

RoHS Compliant

Mechanical Characteristics

Package: SOT-23

Lead Finish: Matte Tin

• Case Material: "Green" Molding Compound.

Moisture Sensitivity: Level 3 per J-STD-020

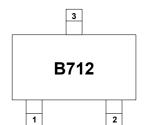
Terminal Connections: See Diagram Below

· Marking Information: See Below

<u>Applications</u>

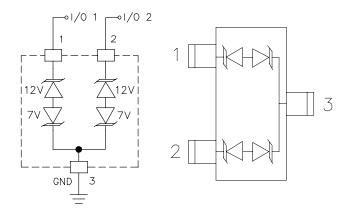
- Wireless System
- Networks
- Portable Instrumentation
- RS485 Ports

Marking Information



B712 = Device Marking Code

Dimensions and Pin Configuration



Circuit Schematic

Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size		
ASM712	3000/Tape & Reel	7 inch		



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

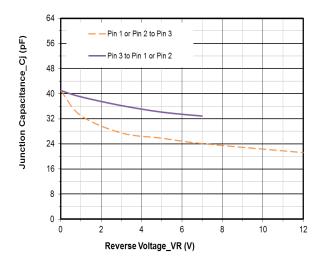
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	325	W	
Peak Pulse Current (8/20µs)	Ірр	13	Α	
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±30	N.V	
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	

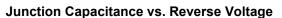
Electrical Characteristics (T_A=25°C unless otherwise specified)

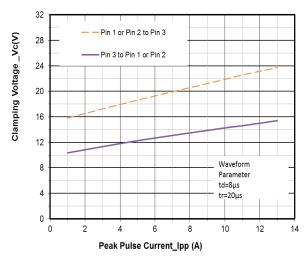
		Pin 1 to 3 and 2 to 3		Pin 3 to 1 and 3 to 2					
		(1	2V T\	/ S)	(7	V TV	S)		
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			12			7	٧	
Breakdown Voltage	VBR	13.3			7.5			V	IT = 1mA
Reverse Leakage Current	I _R			0.5			0.5	μΑ	VR = VRWM
Clamping Voltage	Vc			20			14	V	IPP = 5A (8 x 20µs pulse)
Clamping Voltage	Vc			25			16	٧	IPP = 13A (8 x 20μs pulse)
Junction Capacitance	СЛ		40			40		pF	VR = 0V, f = 1MHz
Junction Capacitance	СЛ		20			30		pF	VR = VRWM, f = 1MHz



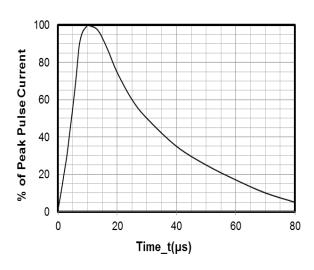
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



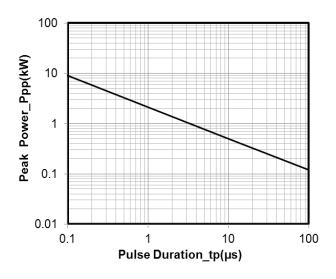




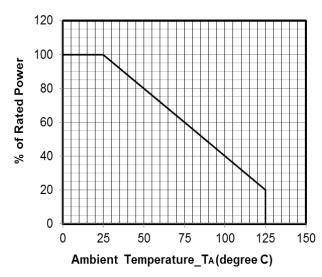
Clamping Voltage vs. Peak Pulse Current



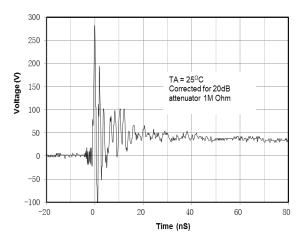
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



Power Derating Curve



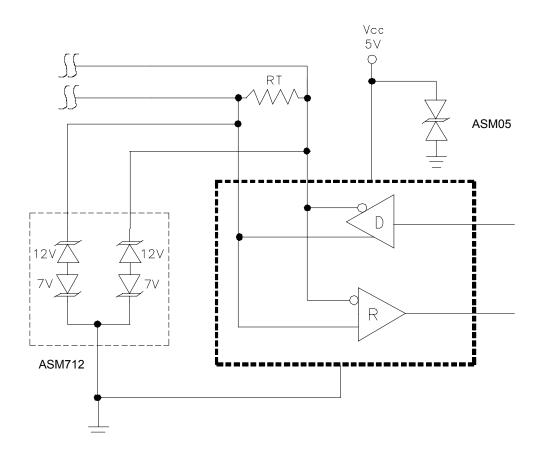
ESD Clamping Voltage

8 kV Contact per IEC61000-4-2



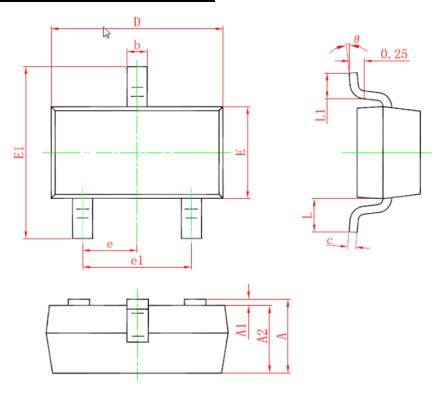
ASM712 on RS-485 Data Lines Application

EIA RS-485 specifies a ±7V ground difference between devices on the bus. This permits the bus voltage to range from +12V (5V + 7V) to -7V (0 - 7V). The ASM712 is designed to protect two RS-485 data lines in extended common mode applications. The ASM712 may be used to protect devices from transient voltages resulting from ESD, EFT, and light ning. The device is designed with asymmetrical operating voltages for optimum protection. The TVS diodes at pins 1 and 2 have a working voltage of 12volts. These pins are connected to the differential data line pairs. The TVS diodes at pin 3 have a working voltage of 7volts. Pin 3 is connected to ground. The internal TVS diodes of the ASM712 will protect the transceiver input from positive transient voltage spikes greater than 12V and negative spikes greater than 7V.





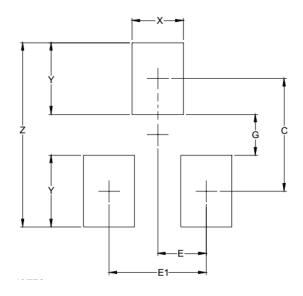
SOT-23 Package Outline Drawing



	DIMENSIONS						
	l l	MILLIMETER	.S	INCHES			
SYM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.90		1.15	0.035		0.045	
A1	0.00		0.10	0.000		0.004	
A2	0.90		1.05	0.035		0.041	
b	0.30		0.50	0.012		0.020	
С	0.08		0.15	0.003		0.006	
D	2.80		3.00	0.110		0.118	
Е	1.20		1.40	0.047		0.055	
E1	2.25		2.25	0.089		0.100	
е		0.95TYP		0.037TYP			
e1	1.80		2.00	0.071		0.079	
L		0.55REF		0.022REF			
L1	0.30		0.50	0.012		0.020	
Θ	0°		8°	0°		8°	



Suggested Land Pattern



SYM	DIMENSIONS				
	INCHES	MILLIMETERS			
С	0.087	(2.20)			
Е	0.037	0.95			
E1	0.075	1.90			
G	0.031	0.80			
Х	0.039	1.00			
Υ	0.055	1.40			
Z	0.141	3.60			

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